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TPS54308 ZHCSGD3-JUNE 2017

采用 SOT23 封装的 TPS54308 4.5V 至 28V 输入、 3A 输出、350kHz 同步 FCCM 降压转换器

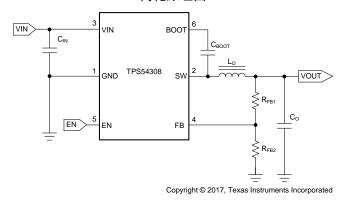
1 特性

- 4.5V 至 28V 宽输入电压范围
- 集成 85mΩ 和 40 mΩ 金属氧化物半导体场效应晶 体管 (MOSFET),持续输出电流为 3A
- 关断电流低至 2µA,静态电流为 300µA
- 内部 5ms 软启动
- 350kHz 固定开关频率
- 峰值电流模式控制
- 内部环路补偿
- 采用打嗝模式为两个 MOSFET 提供过流保护
- 过压保护
- 热关断
- 小外形尺寸晶体管 (SOT)-23 (6) 封装
- 使用 TPS54308 并借助 WEBENCH[®] 电源设计器 创建定制设计方案

2 应用

- 12V 和 24V 分布式电源总线供电
- 工业应用
- 白色家电
- 消费类应用
 - 音频
 - 机顶盒 (STB)、数字电视 (DTV)
 - 打印机

简化原理图



3 说明

TPS54308 是一款输入电压范围为 4.5V 至 28V 的 3A 同步降压转换器。该器件包含两个集成式开关场效应晶体管 (FET) 并且具备内部回路补偿和 5ms 内部软启动功能,可降低组件数。

通过集成 MOSFET 并采用 SOT-23 封装, TPS54308 获得了高功率密度,并且在印刷电路板 (PCB) 上的占 用空间非常小。

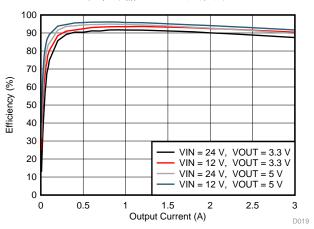
在轻负载条件下,TPS54308 以强制连续导通模式 (FCCM)运行,开关频率在整个负载范围内维持在一个 近乎恒定的水平。

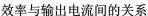
高侧 MOSFET 上的逐周期电流限制功能可在过载条件 下保护转换器并通过防止电流失控的低侧 MOSFET 续 流电流限制功能实现功能增强。当过流持续时间超出预 设时间时,将触发打嗝模式保护功能。

器件信息(1)

器件型号	封装	封装尺寸(标称值)			
TPS54308	SOT-23 (6)	1.60mm x 2.90mm			

(1) 如需了解所有可用封装,请参阅数据表末尾的可订购产品附录。







INSTRUMENTS

Texas

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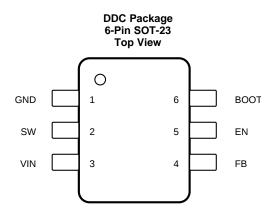
4 修订历史记录

注: 之前版本的页码可能与当前版本有所不同。

日期	修订版本	注意
2017 年 6 月	*	初始发行版。



5 Pin Configuration and Functions



Pin Functions

PI	N	TYPE ⁽¹⁾	DESCRIPTION	
NAME	NO.		DESCRIPTION	
BOOT	6	0	Supply input for the high-side NFET gate drive circuit. Connect a $0.1\mbox{-}\mu\text{F}$ capacitor between BOOT and SW pins.	
EN	5	I	his pin is the enable pin. Float the EN pin to enable.	
FB	4	I	Converter feedback input. Connect to output voltage with feedback resistor divider.	
GND	1	_	Ground pin Source terminal of low-side power NFET as well as the ground terminal for controller circuit. Connect sensitive VFB to this GND at a single point.	
SW	2	0	Switch node connection between high-side NFET and low-side NFET.	
VIN	3	-	Input voltage supply pin. The drain terminal of high-side power NFET.	

(1) O = Output; I = Input

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		1	NIN	MAX	UNIT
	VIN	-	-0.3	30	V
Input voltage range, VI	EN	-	-0.3	7	V
	FB	-	-0.3	7	V
	BOOT-SW	-	-0.3	7	V
Output voltage range, V _O	SW	-	-0.3	30	V
	SW (20 ns transient)		-5	30	V
Operating junction temperature,	TJ	-	-40	150	°C
Storage temperature range, Tstg	I	-	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±4000	V
V _(ESD)	discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
		VIN	4.5	28	V
V _I Input voltage range	EN	-0.1	7	V	
	FB	-0.1	7	V	
V		BOOT-SW	-0.1	7	V
V _o O	Output voltage range	SW	-0.1	28	V
TJ	T _J Operating junction temperature		-40	125	°C

6.4 Thermal Information

		TPS54308	
	THERMAL METRIC ⁽¹⁾	DDC (SOT-23)	UNIT
		6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	87.1	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	35.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	14.4	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.9	°C/W
Ψјв	Junction-to-board characterization parameter	14.2	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.



6.5 Electrical Characteristics

The electrical ratings specified in this section apply to all specifications in this document, unless otherwise noted. These specifications are interpreted as conditions that do not degrade the device parametric or functional specifications for the life of the product containing it. $T_J = -40^{\circ}$ C to +125°C, $V_{IN} = 4.5$ V to 28 V, (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT SUPP	LY					
V _{IN}	Input voltage range		4.5		28	V
lq	Non switching quiescent current	EN =5 V, VFB = 1 V		300		μA
I _{OFF}	Shut down current	EN = GND		2		μA
		Rising V _{IN}	3.8	4.1	4.45	V
V _{IN(UVLO)}	VIN under voltage lockout	Falling V _{IN}	3.3	3.6	3.9	V
. ,	Hysteresis		400	480	600	mV
ENABLE (EN	PIN)					
V _(EN_RISING)	E a chia dhara chiaid	Rising		1.21	1.28	V
V _(EN_FALLING)	Enable threshold	Falling	1.1	1.19		V
I _(EN_INPUT)	Input current	V _{EN} = 1 V		0.7		μA
I _(EN_HYS)	Hysteresis current	V _{EN} = 1.5 V		1.55		μA
FEEDBACK	AND ERROR AMPLIFIER					
V _{FB}	Feedback Voltage	V _{IN} = 12 V	0.581	0.596	0.611	V
POWER STA	GE					
R _(HSD)	High-side FET on resistance	$T_A = 25^{\circ}C, V_{BST} - SW = 6 V$		85		mΩ
R _(LSD)	Low-side FET on resistance	$T_A = 25^{\circ}C, V_{IN} = 12$		40		mΩ
CURRENT LI	МІТ					
I _(LIM_HS)	High side current limit	Maximum inductor peak current	4	5	5.9	А
I _(LIM_LS)	Low side source current limit	Maximum inductor valley current	3.1	4	5.5	А
I(LIM_LSSOC)	Low side sink current limit		1.75	2.8	3.85	А
OSCILLATOR	र					
F _{sw}	Centre switching frequency		255	350	445	kHz
OVER TEMP	ERATURE PROTECTION					
	Rising temperature			165		°C
Thermal Shutdown ⁽¹⁾	Hysteresis			10		°C
Chataown	Hiccup time			32768		Cycles

(1) Not production tested

6.6 Timing Requirements

		MIN	TYP	MAX	UNIT		
OVER CURREN	OVER CURRENT PROTECTION						
t _{HIC_WAIT}	Hiccup wait time		512		Cycles		
t _{HIC_RESTART}	Hiccup time before restart		16384		Cycles		
t _{SS}	Soft-start time		5		ms		
ON TIME CONTROL							
t _{MIN_ON} ⁽¹⁾	Minimum on time, measured at 90% to 90% and 1-A loading		110		ns		

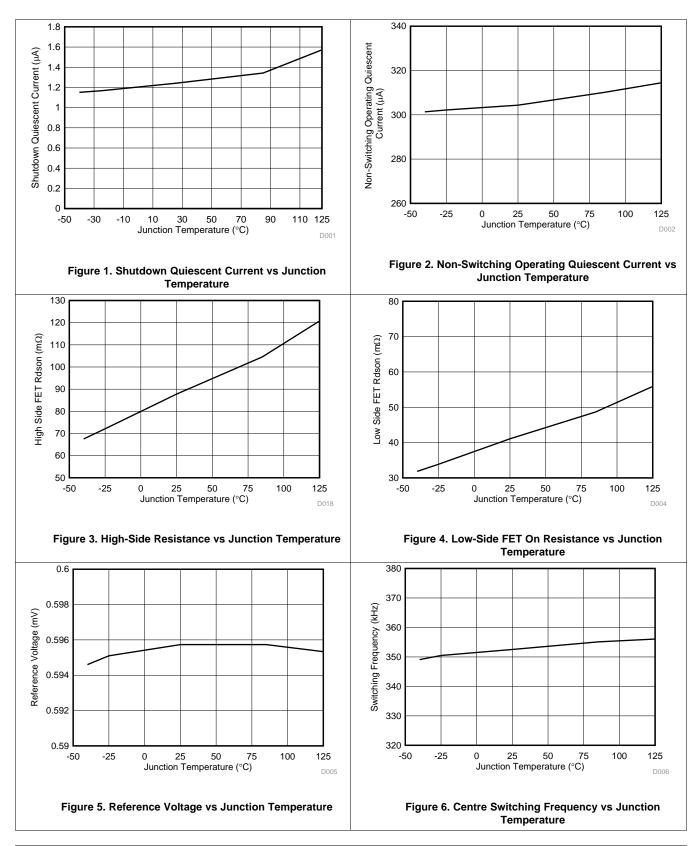
(1) Not production tested

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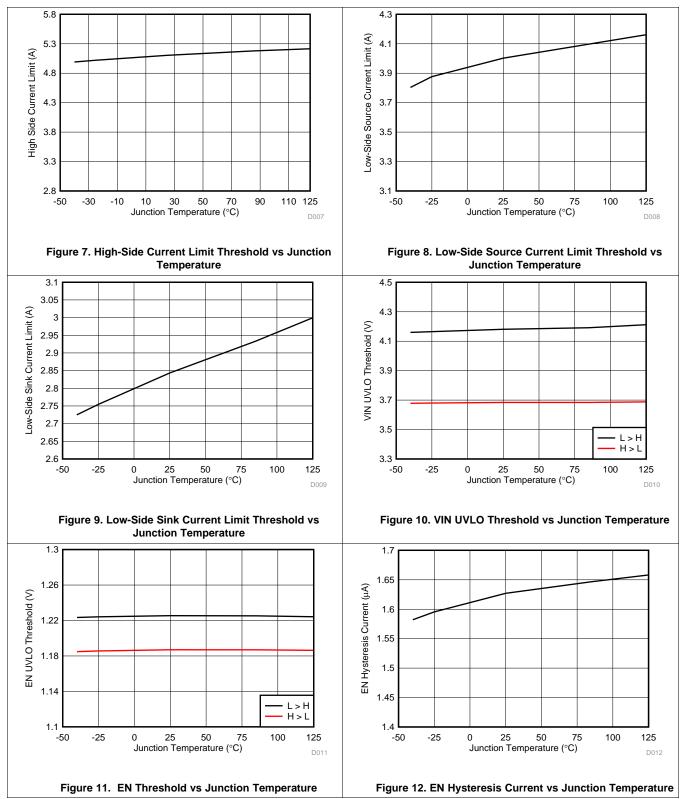
6.7 Typical Characteristics

V_{IN} = 12, unless otherwise specified





Typical Characteristics (continued)



7 Detailed Description

7.1 Overview

The device is a 28-V, 3-A, synchronous step-down (buck) converter with two integrated n-channel MOSFETs. To improve performance during line and load transients the device implements a constant-frequency, peak current mode control which reduces output capacitance. The optimized internal compensation network minimizes the external component counts and simplifies the control loop design.

The TPS54308's switching frequency is fixed to 350 kHz, and this device operates in continuous conduction mode (FCCM) during light load conditions. During FCCM, the switching frequency is maintained at an almost constant level over the entire load range which is suitable fro applications requiring tight control of the switching frequency and output voltage ripple at the cost of lower efficiency under light load.

The TPS54308 starts switching at VIN equal to 4.5 V. The operating current is 300 μ A typically when not switching and under no load. When the device is disabled, the supply current is 2 μ A typically.

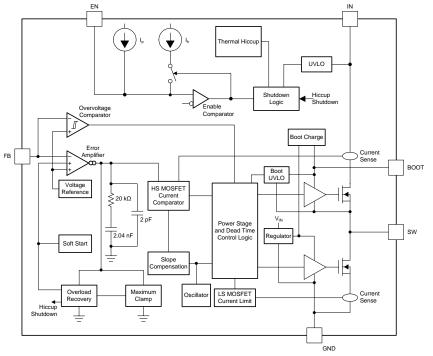
The integrated 85-m Ω high-side MOSFET and 40-m Ω low-side MOSFET allow for high efficiency power supply designs with continuous output currents up to 3 A.

The TPS54308 reduces the external component count by integrating the boot recharge diode. The bias voltage for the integrated high-side MOSFET is supplied by an external capacitor on the BOOT to PH pins. The boot capacitor voltage is monitored by an UVLO circuit and will turn the high-side MOSFET off when the voltage falls below a preset threshold of 2.1 V typically.

The device minimizes excessive output overvoltage transients by taking advantage of the overvoltage comparator. When the regulated output voltage is greater than 118% of the nominal voltage, the overvoltage comparator is activated, and the high-side MOSFET is turned off and masked from turning on until the output voltage is lower than 104%.

The TPS54308 device has internal 5-ms soft-start time to minimize inrush currents.

7.2 Functional Block Diagram



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7.3 Feature Description

7.3.1 Fixed-Frequency PWM Control

The device uses a fixed-frequency, peak current-mode control. The output voltage is compared through external resistors on the FB pin to an internal voltage reference by an error amplifier. An internal oscillator initiates the turn on of the high-side power switch. The error amplifier output is compared to the current of the high-side power switch. When the power-switch current reaches the error amplifier output voltage level, the high side power switch is turned off and the low-side power switch is turned on. The error amplifier output voltage increases and decreases as the output current increases and decreases. The device implements a current-limit by clamping the error amplifier voltage to a maximum level and also implements a minimum clamp for improved transient-response performance.

7.3.2 Force Continuous Conduction Mode (FCCM)

The TPS54308 is designed to operate in forced continuous conduction mode (FCCM) during light load conditions. During FCCM, the switching frequency is maintained at an almost constant level over the entire load range which is suitable fro applications requiring tight control of the switching frequency and output voltage ripple at the cost of lower efficiency under light load. For some audio application, this mode can help avoid switching frequency drop into audible range that may introduce some "noise".

7.3.3 Error Amplifier

The device has a trans-conductance amplifier as the error amplifier. The error amplifier compares the FB voltage to the lower of the internal soft-start voltage or the internal 0.596-V voltage reference. The transconductance of the error amplifier is 240 μ A/V typically. The frequency compensation components are placed internal between the output of the error amplifier and ground.

7.3.4 Slope Compensation and Output Current

The device adds a compensating ramp to the signal of the switch current. This slope compensation prevents sub-harmonic oscillations as the duty cycle increases. The available peak inductor current remains constant over the full duty-cycle range.

7.3.5 Enable and Adjusting Undervoltage Lockout

The EN pin provides electrical on and off control of the device. When the EN pin voltage exceeds the threshold voltage, the device begins operation. If the EN pin voltage is pulled below the threshold voltage, the regulator stops switching and enters the low-quiescent (IQ) state.

The EN pin has an internal pullup-current source which allows the user to float the EN pin to enable the device. If an application requires control of the EN pin, use open-drain or open-collector output logic to interface with the pin.

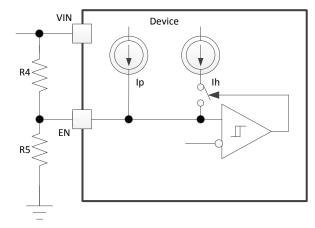
The device implements internal undervoltage-lockout (UVLO) circuitry on the VIN pin. The device is disabled when the VIN pin voltage falls below the internal VIN UVLO threshold. The internal VIN UVLO threshold has a hysteresis of 480 mV.

If an application requires a higher UVLO threshold on the VIN pin, then the EN pin can be configured as shown in Figure 13. When using the external UVLO function, setting the hysteresis at a value greater than 500 mV is recommended.

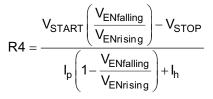
The EN pin has a small pull-up current, Ip, which sets the default state of the pin to enable when no external components are connected. The pull-up current is also used to control the voltage hysteresis for the UVLO function because it increases by Ih when the EN pin crosses the enable threshold. Use Equation 1 and Equation 2 to calculate the values of R4 and R5 for a specified UVLO threshold.



Feature Description (continued)







Where:

$$\begin{split} I_{p} &= 0.7 \; \mu A \\ I_{h} &= 1.55 \; \mu A \\ V_{ENfalling} &= 1.19 \; V \\ V_{ENrising} &= 1.22 \; V \\ R5 &= \frac{R4 \times V_{ENfalling}}{V_{STOP} - V_{ENfalling} + R4\left(I_{p} + I_{h}\right)} \end{split}$$

(1)

(2)

7.3.6 Safe Startup into Pre-Biased Outputs

The device has been designed to prevent the low-side MOSFET from discharging a pre-biased output. During monotonic pre-biased startup, both high-side and low-side MOSFETs are not allowed to be turned on until the internal soft-start voltage is higher than FB pin voltage.

7.3.7 Voltage Reference

The voltage reference system produces a precise $\pm 2.5\%$ voltage-reference over temperature by scaling the output of a temperature stable bandgap circuit. The typical voltage reference is designed at 0.596 V.

7.3.8 Adjusting Output Voltage

The output voltage is set with a resistor divider from the output node to the FB pin. It is recommended to use divider resistors with 1% tolerance or better. Start with 100 k Ω for the upper resistor divider, use Equation 3 to calculate the output voltage. To improve efficiency at light loads consider using larger value resistors. If the values are too high the regulator is more susceptible to noise and voltage errors from the FB input current are noticeable.

$$V_{OUT} = V_{ref} \times \left[\frac{R2}{R3} + 1 \right]$$

7.3.9 Internal Soft-Start

The TPS54308 device uses the internal soft-start function. The internal soft start time is set to 5 ms typically.



7.3.10 Bootstrap Voltage (BOOT)

The TPS54308 has an integrated boot regulator and requires a $0.1-\mu$ F ceramic capacitor between the BOOT and SW pins to provide the gate drive voltage for the high-side MOSFET. A ceramic capacitor with an X7R or X5R grade dielectric is recommended because of the stable characteristics over temperature and voltage. To improve drop out, the TPS54308 is designed to operate at 100% duty cycle as long as the BOOT to SW pin voltage is greater than 2.1 V typically.

7.3.11 Overcurrent Protection

The device is protected from overcurrent conditions by cycle-by-cycle current limiting on both the high-side MOSFET and the low-side MOSFET.

7.3.11.1 High-Side MOSFET Overcurrent Protection

The device implements current mode control which uses the internal COMP voltage to control the turn off of the high-side MOSFET and the turn on of the low-side MOSFET on a cycle-by-cycle basis. During each cycle, the switch current and the current reference generated by the internal COMP voltage are compared. When the peak switch current intersects the current reference the high-side switch turns off.

7.3.11.2 Low-Side MOSFET Overcurrent Protection

While the low-side MOSFET is turned on, the conduction current is monitored by the internal circuitry. During normal operation the low-side MOSFET sources current to the load. At the end of every clock cycle, the low-side MOSFET sourcing current is compared to the internally set low-side sourcing current-limit. The inductor valley current is exceeded the low-side source current limit, the high-side MOSFET does not turn on and the low-side MOSFET stays on for the next cycle. The high-side MOSFET turns on again when the inductor valley current is below the low-side sourcing current-limit at the start of a cycle as shown in Figure 14.

Furthermore, if an output overload condition occurs for more than the hiccup wait time, which is programmed for 512 switching cycles, the device shuts down and restarts after the hiccup time of 16384 cycles. The hiccup mode helps to reduce the device power dissipation under severe overcurrent conditions.

The low-side MOSFET may also sink current from load. If the low-side sinking current limit is exceeded, the lowsdie MOSFET is turned off immediatedly for the rest of that clock cycle. In this scenario both MOSFET are off until the start of the next cycle.

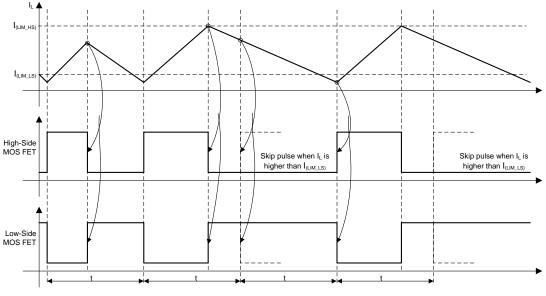


Figure 14. Overcurrent Protection for Both MOSFETs



Feature Description (continued)

7.3.12 Output Overvoltage Protection (OVP)

The TPS54308 incorporates an overvoltage transient protection (OVTP) circuit to minimize output voltage overshoot when recovering from output fault conditions or strong unload transients. The OVTP circuit includes an overvoltage comparator to compare the FB pin voltage and internal thresholds. When the FB pin voltage goes above 118% x Vref, the high-side MOSFET is forced off. When the FB pin voltage falls below 104% x Vref, the high-side MOSFET is enabled again.

7.3.13 Thermal Shutdown

The internal thermal-shutdown circuitry forces the device to stop switching if the junction temperature exceeds 165°C typically. When the junction temperature drops below 155°C typically, the internal thermal-hiccup timer begins to count. The device reinitiates the power-up sequence after the built-in thermal-shutdown hiccup time (32768 cycles) is over.

7.4 Device Functional Modes

When the input voltage is above the UVLO threshold, the TPS54308 operate in force continuous conduction mode (FCCM), during FCCM, the switching frequency is maintained at an almost constant level over the entire load range.



8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TPS54308 is typically used as a step down converter, which converts an input voltage from 8 V - 28 V to a fixed output voltage of 3.3 V.

8.2 Typical Application

8.2.1 TPS54308 8-V to 28-V Input, 5-V Output Converter

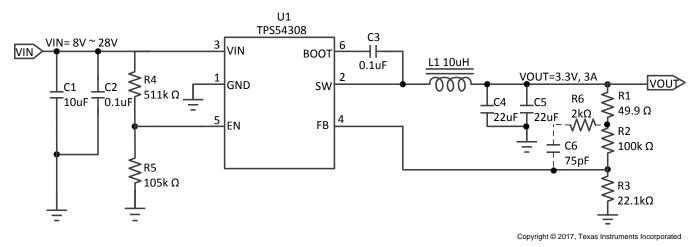


Figure 15. 5-V, 3-A Reference Design

8.2.2 Design Requirements

For this design example, use the parameters in Table 1.

Table 1. Design Parameters

PARAMETER	VALUE
Input voltage range	8 V to 28 V
Output voltage	3.3 V
Output current	3 A
Transient response, 1.5-A load step	$\Delta V_{OUT} = \pm 5 \%$
Input ripple voltage	400 mV
Output voltage ripple	30 mVpp
Switching frequency	350 kHz

8.2.3 Detailed Design Procedure

8.2.3.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the TPS54308 device with the WEBENCH® Power Designer.

- 1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
- 2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
- 3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- · Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

8.2.3.2 Input Capacitor Selection

The device requires an input decoupling capacitor and a bulk capacitor is needed depending on the application. A ceramic capacitor over 10 μ F is recommended for the decoupling capacitor. An additional 0.1- μ F capacitor (C2) from VIN to GND is optional to provide additional high frequency filtering. The capacitor voltage rating needs to be greater than the maximum input voltage.

Use Equation 4 to calculate the input ripple voltage (ΔV_{IN}).

$$\Delta V_{\text{IN}} = \frac{I_{\text{OUT}(\text{MAX})} \times 0.25}{C_{\text{BULK}} \times f_{\text{sw}}} + \left(I_{\text{OUT}(\text{MAX})} \times \text{ESR}_{\text{MAX}}\right)$$

where:

C_{BULK} is the bulk capacitor value

f_{SW} is the switching frequency

I_{OUT(MAX)} is the maximum loading current

ESR_{MAX} is maximum series resistance of the bulk capacitor

The maximum RMS (root mean square) ripple current must also be checked. For worst case conditions, use Equation 5 to calculate $I_{CIN(RMS)}$.

$$I_{CIN(RMS)} = \frac{I_{OUT(MAX)}}{2}$$
(5)

The actual input-voltage ripple is greatly affected by parasitic associated with the layout and the output impedance of the voltage source. Design Requirements show the actual input voltage ripple for this circuit which is larger than the calculated value. This measured value is still below the specified input limit of 400 mV. The maximum voltage across the input capacitors is VIN (MAX) + Δ VIN/2. The selected bypass capacitor is rated for 35 V and the ripple current capacity is greater than 2 A. Both values provide ample margin. The maximum ratings for voltage and current must not be exceeded under any circumstance.

(4)



8.2.3.3 Bootstrap Capacitor Selection

A 0.1-µF ceramic capacitor must be connected between the BOOT to SW pin for proper operation. It is recommended to use a ceramic capacitor.

8.2.3.4 Output Voltage Set Point

The output voltage of the TPS54308 device is externally adjustable using a resistor divider network. In the application circuit of Figure 15, this divider network is comprised of R2 and R3. Use Equation 6 and Equation 7 to calculate the relationship of the output voltage to the resistor divider.

$$R3 = \frac{R2 \times V_{ref}}{V_{OUT} - V_{ref}}$$

$$V_{OUT} = V_{ref} \times \left[\frac{R2}{R3} + 1\right]$$
(6)
(7)

Select a value of R2 to be approximately 100 k Ω . Slightly increasing or decreasing R3 can result in closer output voltage matching when using standard value resistors. In this design, R2 = 100 k Ω and R3 = 22.1 k Ω which results in a 3.3-V output voltage. The 49.9- Ω resistor, R1, is provided as a convenient location to break the control loop for stability testing.

8.2.3.5 Undervoltage Lockout Set Point

The undervoltage lockout (UVLO) set point can be adjusted using the external-voltage divider network of R4 and R5. R4 is connected between the VIN and EN pins of the TPS54308 device. R5 is connected between the EN and GND pins. The UVLO has two thresholds, one for power up when he input voltage is rising and one for power down or brown outs when the input voltage is falling. For the example design, the minimum input voltage is 8 V, so the start voltage threshold is set to 6.74 V and the stop voltage threshold is set to 5.83 V. Use Equation 1 and Equation 2 to calculate the values for the upper and lower resistor values of R4 and R5.

8.2.3.6 Output Filter Components

Two components must be selected for the output filter, the output inductor (L_0) and C_0 .

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8.2.3.6.1 Inductor Selection

Use Equation 8 to calculate the minimum value of the output inductor (L_{MIN}).

$$L_{MIN} = \frac{V_{OUT} \times \left(V_{IN(MAX)} - V_{OUT}\right)}{V_{IN(MAX)} \times K_{IND} \times I_{OUT} \times f_{sw}}$$

(8)

Where:

 K_{IND} is a coefficient that represents the amount of inductor ripple current relative to the maximum output current.

In general, the value of K_{IND} is at the discretion of the designer; however, the following guidelines may be used. For designs using low-ESR output capacitors, such as ceramics, a higher K_{IND} can be used. When using higher ESR output capacitors, $K_{IND} = 0.2$ yields better results.

For this design example, use $K_{IND} = 0.3$. The minimum inductor value is calculated as 9.24 μ H. For this design, a close standard value of 10 μ H was selected for L_{MIN} .

For the output filter inductor, the RMS current and saturation current ratings must not be exceeded. Use Equation 9 to calculate the RMS inductor current ($I_{L(RMS)}$).

$$I_{L(MAX)} = \sqrt{I_{OUT(MAX)}^{2} + \frac{1}{12} \times \left(\frac{V_{OUT} \times \left(V_{IN(MAX)} - V_{OUT}\right)}{V_{IN(MAX)} \times L_{O} \times f_{SW} \times 0.8}\right)^{2}}$$
(9)

Use Equation 10 to calculate the peak inductor current $(I_{L(PK)})$.

$$I_{L(PK)} = I_{OUT(MAX)} + \frac{V_{OUT} \times \left(V_{IN(MAX)} - V_{OUT}\right)}{1.6 \times V_{IN(MAX)} \times L_{O} \times f_{SW}}$$
(10)

Smaller or larger inductor values can be used depending on the amount of ripple current the designer wants to allow as long as the other design requirements are met. Larger value inductors have lower AC current and result in lower output voltage ripple. Smaller inductor values increase AC current and output voltage ripple.

8.2.3.6.2 Output Capacitor Selection

Consider three primary factors when selecting the value of the output capacitor. The output capacitor determines the modulator pole, the output voltage ripple, and how the regulator responds to a large change in load current. The output capacitance must be selected based on the more stringent of these three criteria.

The desired response to a large change in the load current is the first criterion. The output capacitor must supply the load with current when the regulator cannot. This situation occurs if the desired hold-up times are present for the regulator. In this case, the output capacitor must hold the output voltage above a certain level for a specified amount of time after the input power is removed. The regulator is also temporarily unable to supply sufficient output current if a large, fast increase occurs affecting the current requirements of the load, such as a transition from no load to full load. The regulator usually requires two or more clock cycles for the control loop to notice the change in load current and output voltage and to adjust the duty cycle to react to the change. The output capacitor must be large enough to supply the difference in current for 2 clock cycles while only allowing a tolerable amount of drop in the output voltage. Use Equation 11 to calculate the minimum required output capacitance.



$$C_{O} > \frac{2 \times \Delta I_{OUT}}{f_{sw} \times \Delta V_{OUT}}$$

where:

 ΔI_{OUT} is the change in output current f_{SW} is the switching frequency of the regulator $\Delta V_{(OUT)}$ b is the allowable change in the output voltage

For this example, the transient load response is specified as a 5% change in the output voltage, V_{OUT}, for a load step of 1.5 A. For this example, $\Delta I_{OUT} = 1.5$ A and $\Delta V_{OUT} = 0.05 \times 3.3 = 0.165$ V. Using these values results in a minimum capacitance of 52 µF. This value does not consider the ESR of the output capacitor in the output voltage change. For ceramic capacitors, the ESR is usually small enough to ignore in this calculation.

Equation 12 calculates the minimum output capacitance required to meet the output voltage ripple specification. In this case, the maximum output voltage ripple is 30 mV. Under this requirement, Equation 12 yields 9.9 µF.

$$C_{O} > \frac{1}{8 \times f_{SW}} \times \frac{1}{\frac{V_{OUTripple}}{I_{ripple}}}$$

where:

 f_{SW} is the switching frequency

V_(OUTripple) is the maximum allowable output voltage ripple

 $I_{(ripple)}$ is the inductor ripple current

Use Equation 13 to calculate the maximum ESR an output capacitor can have to meet the output-voltage ripple specification. Equation 13 indicates the ESR should be less than 36 m Ω . In this case, the ESR of the ceramic capacitor is much smaller than 36 m Ω .

$$R_{ESR} < \frac{V_{OUTripple}}{I_{ripple}}$$
(13)

The output capacitor can affect the crossover frequency f_0 . Considering to the loop stability and effect of the internal parasitic parameters, choose the crossover frequency less than 40 kHz without considering the feed forward capacitor. A simple estimation for the crossover frequency without feed forward capacitor C6 is shown in Equation 14, assuming C_{OUT} has small ESR.

$$f_{O} = \frac{5.1}{V_{OUT} \times C_{O}}$$
(14)

Additional capacitance deratings for aging, temperature, and DC bias should be considered which increases this minimum value. For this example, two 22-uF 25-V, X7R ceramic capacitors are used. Capacitors generally have limits to the amount of ripple current they can handle without failing or producing excess heat. An output capacitor that can support the inductor ripple current must be specified. Some capacitor data sheets specify the RMS value of the maximum ripple current. Use Equation 15 to calculate the RMS ripple current that the output capacitor must support. For this application, Equation 15 yields 120 mA for each capacitor.

$$I_{\text{COUT}(\text{RMS})} = \frac{1}{\sqrt{12}} \times \left(\frac{V_{\text{OUT}} \times \left(V_{\text{IN}(\text{MAX})} - V_{\text{OUT}} \right)}{V_{\text{IN}(\text{MAX})} \times L_{\text{O}} \times f_{\text{SW}} \times N_{\text{C}}} \right)$$
(15)

(11)

(12)



8.2.3.6.3 Feed-Forward Capacitor

The TPS54308 is internally compensated and the internal compensation network is composed of two capacitors and one resister shown on the block diagram. Depending on the V_{OUT} , if the output capacitor C_{OUT} is dominated by low ESR (ceramic types) capacitors, it may result in low phase margin. To improve the phase boost an external feedforward capacitor C6 can be added in parallel with R2. C6 is chosen such that phase margin is boosted at the crossover frequency.

Equation 16 for C6 was tested:

$$C6 = \frac{1}{2\pi f_0} \times \frac{1}{R2}$$

(16)

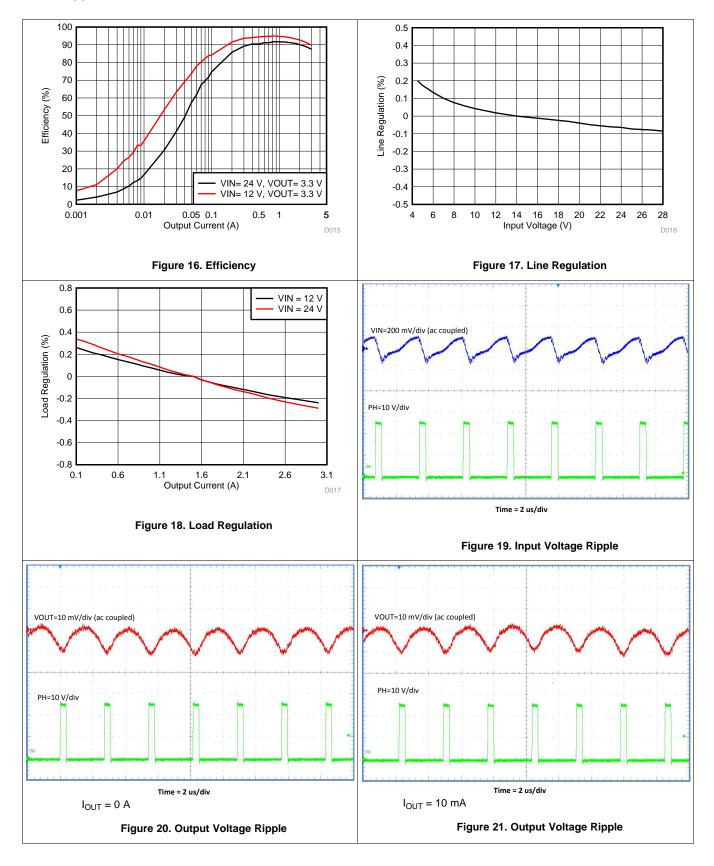
For this design, no need feed-forward capacitor C6 since load transient performance looks good and meet design requirement. If further boosting phase margin for low-ESR (ceramic types) capacitors is desired, useTable 2 as a starting point for the feed-forward capacitor choosing and also recommend in series with one 2-kohm resistor (R6) with this feed-forward capacitor to get better steady-state performance under high V_{IN} with a heavy load.

V _{OUT} (V)	L (µH)	С _{ОՍТ} (µF)	R2 (kΩ)	R3 (kΩ)	C6 (µF)	R6 (kΩ)
1.8	5.6	66	100	49.9	47	2
2.5	6.8	66	100	31.6	47	2
3.3	10	44	100	22.1	75	2
5	15	44	100	13.3	75	2
12	22	44	100	5.23	100	2

Table 2. Recommended Component Values



8.2.4 Application Curves

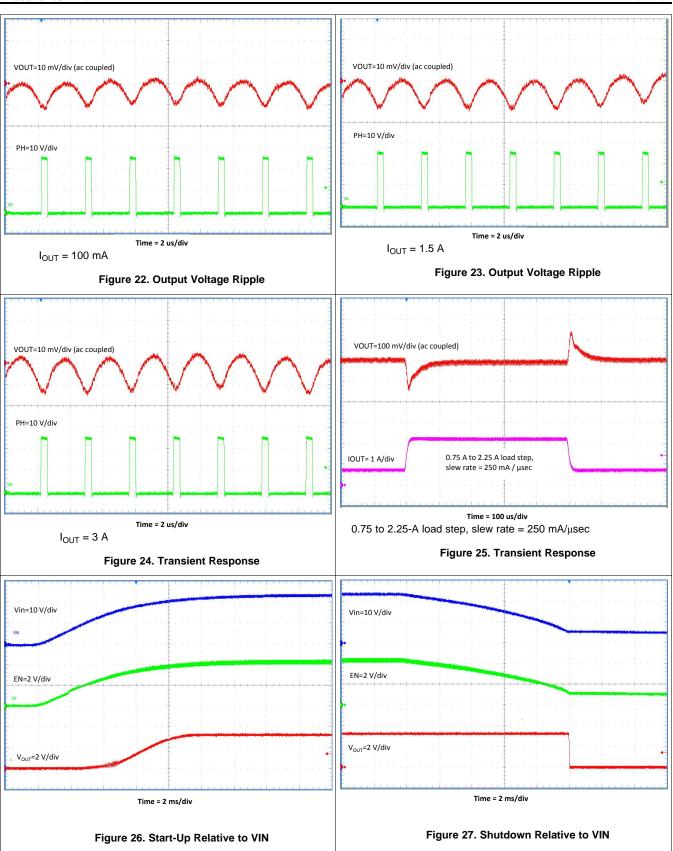


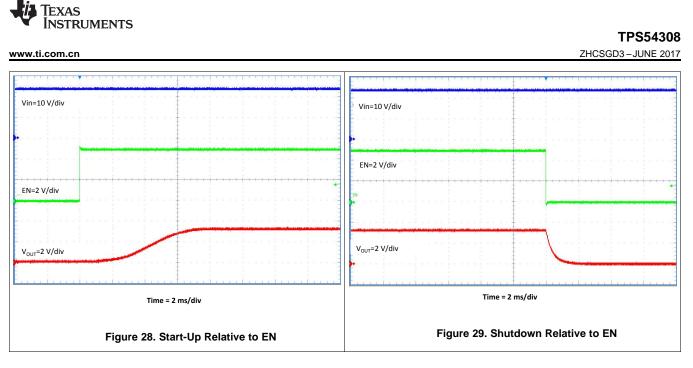
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9 Power Supply Recommendations

The device is designed to operate from an input voltage supply range between 4.5 V and 28 V. This input supply must be well regulated. If the input supply is located more than a few inches from the device or converter, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. An electrolytic capacitor with a value of 47 μ F is a typical choice.

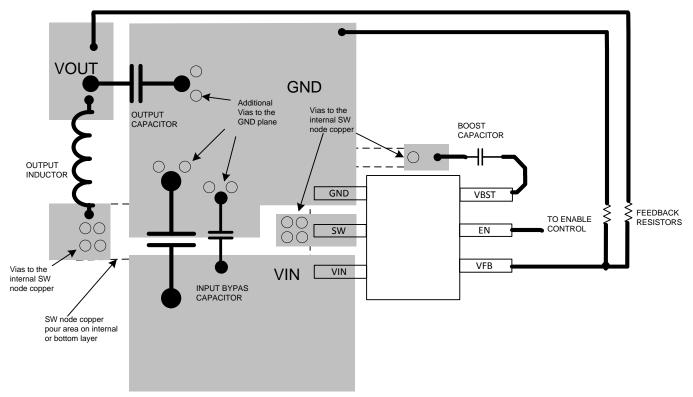
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10 Layout

10.1 Layout Guidelines

- VIN and GND traces should be as wide as possible to reduce trace impedance. The wide areas are also of advantage from the view point of heat dissipation.
- The input capacitor and output capacitor should be placed as close to the device as possible to minimize trace impedance.
- Provide sufficient vias for the input capacitor and output capacitor.
- · Keep the SW trace as physically short and wide as practical to minimize radiated emissions.
- Do not allow switching current to flow under the device.
- A separate VOUT path should be connected to the upper feedback resistor.
- Make a Kelvin connection to the GND pin for the feedback path.
- Voltage feedback loop should be placed away from the high-voltage switching trace, and preferably has ground shield.
- The trace of the VFB node should be as small as possible to avoid noise coupling.
- The GND trace between the output capacitor and the GND pin should be as wide as possible to minimize its trace impedance.



10.2 Layout Example

Figure 30. Board Layout



11 器件和文档支持

11.1 器件支持

11.1.1 开发支持

11.1.1.1 使用 WEBENCH® 工具定制设计方案

单击此处,使用 TPS54308 器件并借助 WEBENCH® 电源设计器创建定制设计方案。

- 1. 在开始阶段键入输出电压 (V_{IN})、输出电压 (V_{OUT}) 和输出电流 (I_{OUT}) 要求。
- 2. 使用优化器拨盘优化关键设计参数,如效率、封装和成本。
- 3. 将生成的设计与德州仪器 (TI) 的其他解决方案进行比较。

WEBENCH Power Designer 提供一份定制原理图以及罗列实时价格和组件可用性的物料清单。

在多数情况下,可执行以下操作:

- 运行电气仿真,观察重要波形以及电路性能
- 运行热性能仿真,了解电路板热性能
- 将定制原理图和布局方案导出至常用 CAD 格式
- 打印设计方案的 PDF 报告并与同事共享

有关 WEBENCH 工具的详细信息,请访问 www.ti.com/WEBENCH。

11.2 接收文档更新通知

要接收文档更新通知,请导航至 TI.com 上的器件产品文件夹。请单击右上角的通知我 进行注册,即可收到任意产品信息更改每周摘要。有关更改的详细信息,请查看任意已修订文档中包含的修订历史记录。

11.3 社区资源

下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商"按照原样"提供。这些内容并不构成 TI 技术规范, 并且不一定反映 TI 的观点;请参阅 TI 的 《使用条款》。

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设计支持 **71 参考设计支持** 可帮助您快速查找有帮助的 E2E 论坛、设计支持工具以及技术支持的联系信息。

11.4 商标

E2E is a trademark of Texas Instruments. WEBENCH is a registered trademark of Texas Instruments. All other trademarks are the property of their respective owners.

11.5 静电放电警告



ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序,可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级,大至整个器件故障。精密的集成电路可能更容易受到损坏,这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

11.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页面包括机械、封装和可订购信息。这些信息是指定器件的最新可用数据。这些数据发生变化时,我们可能不 会另行通知或修订此文档。如欲获取此产品说明书的浏览器版本,请参见左侧的导航栏。



10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS54308DDCR	ACTIVE	SOT-23-THIN	DDC	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	4308	Samples
TPS54308DDCT	ACTIVE	SOT-23-THIN	DDC	6	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	4308	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

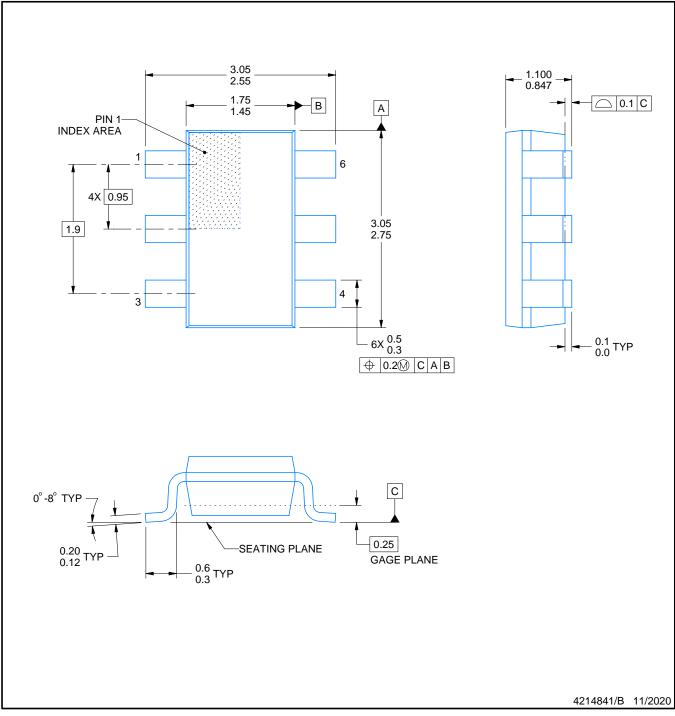
DDC0006A



PACKAGE OUTLINE

SOT - 1.1 max height

SOT



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-193.

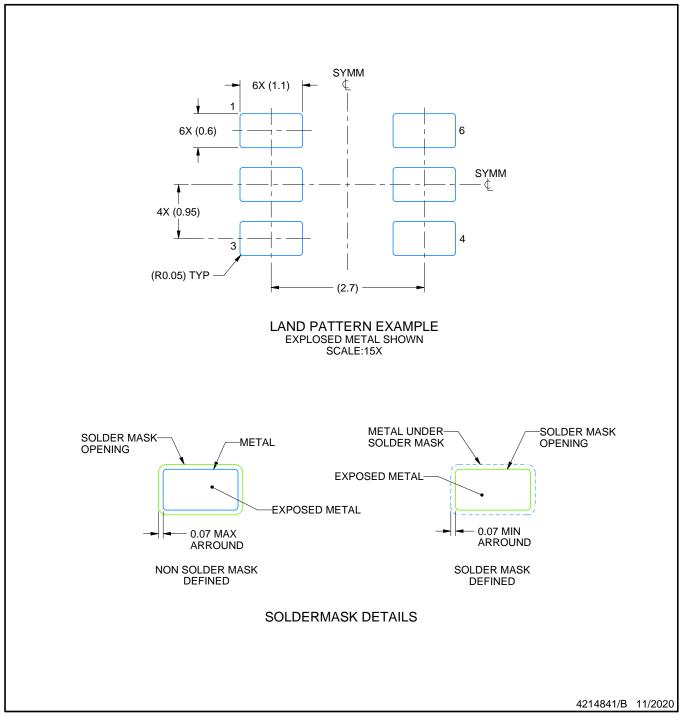


DDC0006A

EXAMPLE BOARD LAYOUT

SOT - 1.1 max height

SOT



NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.

5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

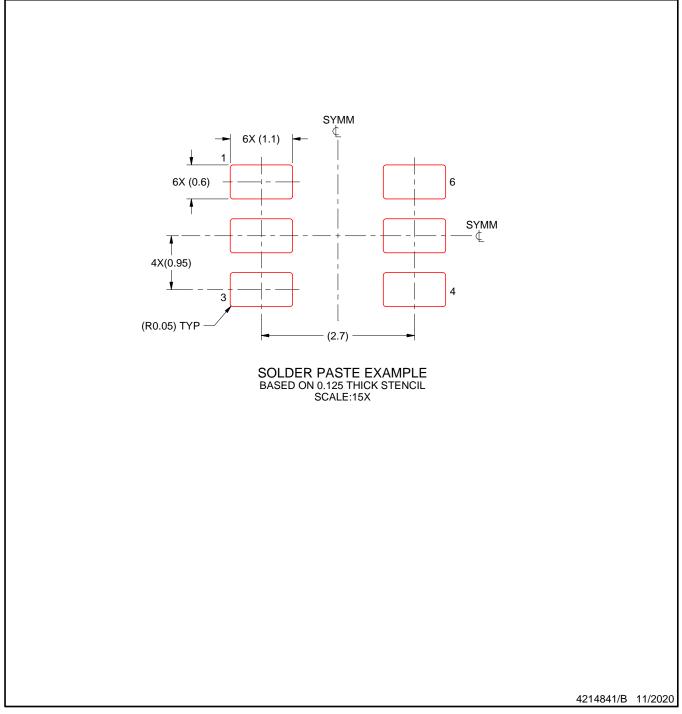


DDC0006A

EXAMPLE STENCIL DESIGN

SOT - 1.1 max height

SOT



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations. 7. Board assembly site may have different recommendations for stencil design.



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